

## IGBT, 1200V, NPT



Images are for reference only

[Inquiry](#)

**Manufacturer:** [ON Semiconductor, LLC](#)

**Package/Case:** TO-247

**Product Type:** Thyristors

**Lifecycle:** Obsolete

## General Description

HGTG18N120BND is based on Non- Punch Through(NPT) IGBT designs. The IGBT is ideal for many high voltage switching applications operating at moderate frequencies where low conduction losses are essential, such as UPS, solar inverter, motor control and power supplies.

## Key Features

140ns at TJ = 150°C Fall time

## Application

Uninterruptible Power Supply

Other Industrial

## Recommended For You

### HGTG20N60B3D

ON Semiconductor, LLC

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### HGTG11N120CND

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### HGTG20N60B3

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### HGTP3N60A4

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### HGTG11N120CN

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### HGTG12N60A4D

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### HGTP7N60C3D

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### HGTG10N120BND

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### HGTP10N120BN

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**HGTG27N120BN**

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**HGTG30N60C3D**

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**HGTG30N60B3**

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**HGTG30N60A4D**

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**HGIP7N60B3D**

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**HGTG40N60B3**

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